Vishay General Semiconductor

# Surface-Mount ESD Capability Rectifier



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PIN 1 O K O PIN 2 O HEATSINK

### LINKS TO ADDITIONAL RESOURCES



| PRIMARY CHARACTERISTICS  |                            |  |  |  |  |
|--|----------------------------|--|--|--|--|
| I <sub>F(AV)</sub>   | 2 x 3 A                    |  |  |  |  |
| V <sub>RRM</sub>   | 100 V, 200 V, 400 V, 600 V |  |  |  |  |
| I <sub>FSM</sub>   | 42 A                       |  |  |  |  |
| V <sub>F</sub> at I <sub>F</sub> = 3 A (T <sub>A</sub> = 125 °C) | 0.94 V                     |  |  |  |  |
| T <sub>J</sub> max.  | 175 °C                     |  |  |  |  |
| Package  | SlimDPAK (TO-252AE)        |  |  |  |  |
| Circuit configuration  | Common cathode             |  |  |  |  |

#### FEATURES

- Very low profile typical height of 1.3 mm
- Ideal for automated placement
- Oxide planar chip junction
- Low forward voltage drop
- ESD capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available - Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **TYPICAL APPLICATIONS**

General purpose, power line polarity protection, in both industry and automotive applications.

### **MECHANICAL DATA**

Case: SlimDPAK (TO-252AE)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant

Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102, M3 and HM3 suffix meets JESD 201 class 2 whisker test

| <b>MAXIMUM RATINGS</b> ( $T_A = 25$ °C unless otherwise noted)                     |          |                                   |             |          |          |          |      |
|--|----------|-----------------------------------|-------------|----------|----------|----------|------|
| PARAMETER  |          | SYMBOL                            | SE60PWBC    | SE60PWDC | SE60PWGC | SE60PWJC | UNIT |
| Device marking code  |          |                                   | SE60PWBC    | SE60PWDC | SE60PWGC | SE60PWJC |      |
| Maximum repetitive peak reverse voltage  |          | V <sub>RRM</sub>                  | 100         | 200      | 400      | 600      | V    |
| Maximum average forward rectified current per device                               |          | ı (1)                             | 6           |          |          |          | Δ    |
| (fig. 1) p   | er diode | I <sub>F(AV)</sub> <sup>(1)</sup> | 3           |          |          |          | A    |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load |          | I <sub>FSM</sub>                  | 42          |          |          |          | A    |
| Peak forward surge current 1 ms square wave on rated load                          |          |                                   | 80          |          |          | Α        |      |
| Operating junction and storage temperature range                                   |          | T <sub>J</sub> , T <sub>STG</sub> | -55 to +175 |          |          |          | °C   |

Note

<sup>(1)</sup> With infinite heatsink

1



RoHS

COMPLIANT

HALOGEN

# SE60PWBC, SE60PWDC, SE60PWGC, SE60PWJC

SE60PWBC, SE60PWDC, SE60PWGC, SE60PWJC



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| <b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted) |   |                           |                               |      |      |      |
|---|---|---------------------------|-------------------------------|------|------|------|
| PARAMETER   | TEST CONDITIONS   |                           | SYMBOL                        | TYP. | MAX. | UNIT |
| Maximum Instantaneous forward voltage   | I <sub>F</sub> = 1.5 A  | T_ = 25 °C                | V <sub>F</sub> <sup>(1)</sup> | 0.94 | -    | V    |
|   | I <sub>F</sub> = 3.0 A  |                           |                               | 1.03 | 1.1  |      |
|   | I <sub>F</sub> = 1.5 A  | - T <sub>A</sub> = 125 °C |                               | 0.84 | -    |      |
|   | I <sub>F</sub> = 3.0 A  |                           |                               | 0.94 | 1.01 |      |
| Deveree ourrent   | Datad V   | T <sub>A</sub> = 25 °C    | I <sub>B</sub> <sup>(2)</sup> | -    | 10   | μA   |
| Reverse current   | Rated V <sub>R</sub>  | T <sub>A</sub> = 125 °C   | IR (=/                        | 12   | 150  |      |
| Typical reverse recovery time   | $I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A}, I_{rr} = 0.25 \text{ A}$ |                           | t <sub>rr</sub>               | 1200 | -    | ns   |
| Typical junction capacitance  | 4.0 V, 1 MHz  |                           | CJ                            | 22   | -    | pF   |

Notes

 $^{(1)}\,$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: pulse width  $\leq$  40 ms

| <b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted) |                                 |  |  |  |  |      |
|--|---------------------------------|--|--|--|--|------|
| PARAMETER  | SYMBOL                          | SYMBOL SE60PWBC SE60PWDC SE60PWGC SE60PWJC |  |  |  | UNIT |
| Typical thermal resistance per device  | R <sub>0JA</sub> (1)(2)         | 63   |  |  |  | °C/W |
| Typical thermal resistance per device  | R <sub>θJM</sub> <sup>(3)</sup> | 2.3  |  |  |  | 0/10 |

#### Notes

<sup>(1)</sup> The heat generated must be less than thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ 

 $^{(2)}$  Free air, mounted on recommended copper pad area; thermal resistance  $R_{\theta JA}$  - junction to ambient

 $^{(3)}$  Mounted on infinite heat sink; thermal resistance  $R_{\theta JM}$  - junction-to-mount

### IMMUNITY TO ELECTRICAL STATIC DISCHARGE TO THE FOLLOWING STANDARDS

| $(T_A = 25 \degree C \text{ unless otherwise noted})$ |                                 |                                |                |       |        |  |
|---|---------------------------------|--------------------------------|----------------|-------|--------|--|
| STANDARD  | TEST TYPE                       | TEST CONDITIONS                | SYMBOL         | CLASS | VALUE  |  |
| AEC-Q101-001  | Human body model (contact mode) | C = 100 pF, R = 1.5 k $\Omega$ | V <sub>C</sub> | H3B   | > 8 kV |  |

| ORDERING INFORMATION (Example) |                 |                        |               |                                    |  |  |
|--------------------------------|-----------------|------------------------|---------------|------------------------------------|--|--|
| PREFERRED P/N                  | UNIT WEIGHT (g) | PREFERRED PACKAGE CODE | BASE QUANTITY | DELIVERY MODE                      |  |  |
| SE60PWJC-M3/I                  | 0.20            | _                      | 4500          | 13" diameter plastic tape and reel |  |  |
| SE60PWJCHM3/I <sup>(1)</sup>   | 0.20            | I                      | 4500          | 13" diameter plastic tape and reel |  |  |

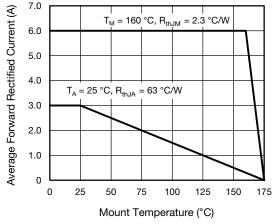
Note

(1) AEC-Q101 qualified

SE60PWBC, SE60PWDC, SE60PWGC, SE60PWJC

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### RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)



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Fig. 1 - Maximum Forward Current Derating Curve

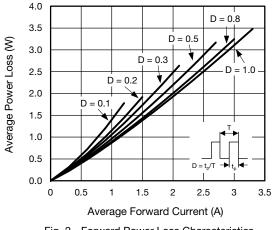
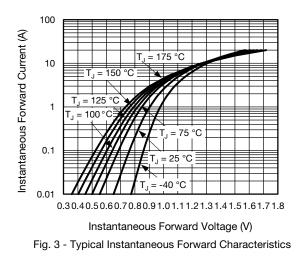
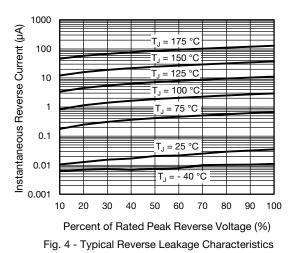
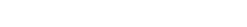
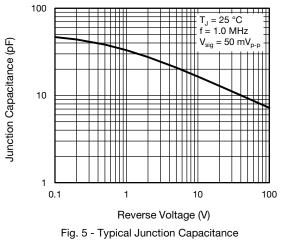


Fig. 2 - Forward Power Loss Characteristics









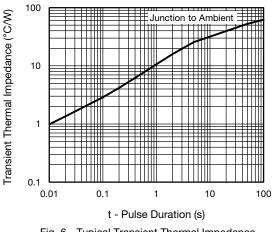


Fig. 6 - Typical Transient Thermal Impedance

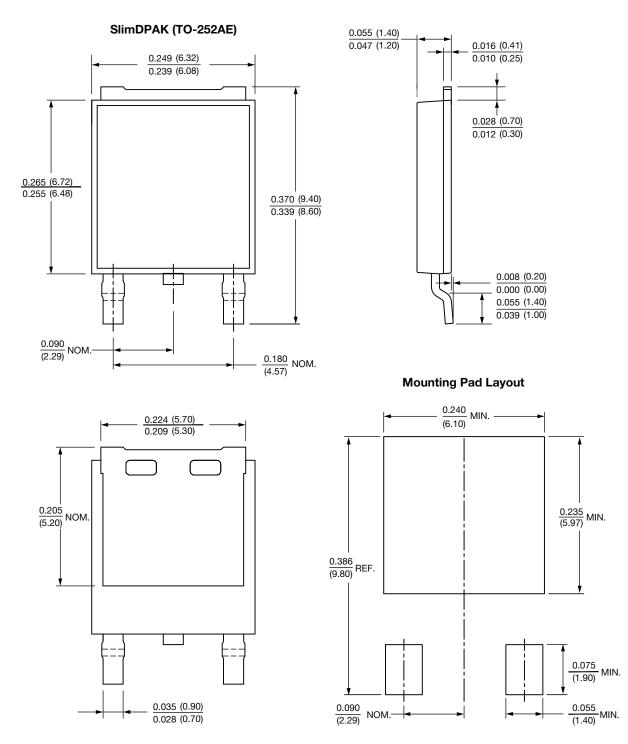
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### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)



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